



Q28C-OTU4-DCO-SKY

MSA Compliant (with select systems) 100GbE/OTU4Base-ZR QSFP28 Transceiver (SMF, 1528.77nm to 1567.13nm, 80km, LC, DOM, CMIS)

Product Description

This MSA compliant (with select systems) with CMIS QSFP28 transceiver provides 100GbE/OTU4Base-ZR throughput up to 80km over single-mode fiber (SMF) using a wavelength of 1528.77nm to 1567.13nm via an LC connector. It can operate at temperatures between 0 and 70C. It has been programmed, uniquely serialized, and tested for data-traffic and application to ensure that it will initialize and perform identically. All of our transceivers comply with Multi-Source Agreement (MSA) standards to provide seamless network integration. Additional product features include Digital Optical Monitoring (DOM) support which allows access to real-time operating parameters. We stand behind the quality of our products and proudly offer a limited lifetime warranty.

Skylane's transceivers are RoHS compliant and lead-free.

Features:

- Hot-Pluggable QSFP28 Form Factor
- Transmission Reach up to 80km Unamplified (Loss Limited) or up to 120km Amplified (Dispersion Limited, Optionally Extendable to 300km)
- IEEE 100G Ethernet (CAUI-4) or ITU-T 100G OTN (OTL4.4) Compliant Host Interface
- Power Dissipation: 5.5W
- Operating Temperature: 0 to 70 Celsius
- Full C-Band Tunable, 50GHz/100GHz Spacing
- Please contact your sales representative for specific system information
- RoHS Compliant and Lead-Free



Applications:

- 100GBase Ethernet
- Duplex Mux

For your product safety, please read the following information carefully before any manipulation of the transceiver:



ESD

This transceiver is specified as ESD threshold 1kV for SFI pins and 2kV for all others electrical input pins, tested per MIL-STD-883G, Method 3015.4 / JESD22-A114-A (HBM). However, normal ESD precautions are still required during the handling of this module.



LASER SAFETY

This is a Class1 Laser Product according to IEC 60825-1:2007. This product complies with 21 CFR 1040.10 and 1040.11 except for deviations pursuant to Laser Notice No. 50, dated (June 24, 2007).

The optical ports of the module need to be terminated with an optical connector or with a dust plug in order to avoid contamination.

Absolute Maximum Ratings

Parameter		Symbol	Min.	Typ.	Max.	Unit	Notes
DC Supply Voltage		V _{cc}	-0.3		3.6	V	
Low-Speed I/O Voltages			-0.3		3.6	V	
Storage Temperature		T _{stg}	-40		85	°C	
Operating Case Temperature	Long-Term	T _c	0		70	°C	1
	Short-Term < 96 Hours		-5		75	°C	
Operating Relative Humidity		RH	5		85	%	
Rx Input Power		PR _{x,in}			10	dBm	
ESD Damage Threshold Human Body Model (HBM)	DC Pins		2000			V	
	RF Pins		1000			V	

Notes:

1. Central office applications.
2. Stresses in excess of the Absolute Maximum Ratings can cause permanent damage to the device. These are absolute stress ratings only. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of the datasheet. Exposure to Absolute Maximum Ratings for extended periods of time can adversely affect device reliability. Use of controls, adjustments, or performance of procedures other than those specified herein may result in hazardous radiation exposure.

Host Interface Modes

Host Interface ID [18]	Host Interface Description [18]	Modulation	Forward Error Correction Code	Nominal Symbol Rate (GBd)	Supported Line Interface IDs [18]
65 [8]	CAUI-4 C2M Without FEC	NRZ	None	25.78125	68, 192, 193
66 [8]	CAUI-4 C2M With RS(528,514) FEC	NRZ	RS(528,514)	25.78125	68, 192, 193
57 [9]	OTL4.4 (ITU-T G.709/Y.1331 G.Sup58)	NRZ	RS(255,239)	27.9525	192, 193

Electrical Characteristics

Parameter		Symbol	Min.	Typ.	Max.	Unit	Notes
Power Supply – General							
Power Supply Voltages			3.135	3.3	3.465	V	Including ripple, droop, and noise below 100kHz
Host RMS Noise Output					25	mV	10Hz - 10MHz
Module RMS Noise Output					15	mV	10Hz - 10MHz
Module Supply Noise Tolerance		PSNRmod			66	mV	10Hz - 10MHz, pk-pk
Module In-Rush		Tip			50	μs	Instantaneous peak duration
		Tinit			500	ms	Initialization time
Power Supply – Low-Power Mode							
Power Dissipation		Plp			1.5	W	
Power Supply Current		Icc,ip,lp			600	mA	Instantaneous peak current
		Icc,sp,lp			495	mA	Sustained peak current
		Icc,lp			478	mA	1, steady state current
Power Supply – High-Power Mode							
Power Dissipation		Php			5.5	W	
Power Supply Current		Icc,ip,hp			2200	mA	Instantaneous peak current
		Icc,sp,hp			1815	mA	Sustained peak current
		Icc,hp			1754	mA	1, steady state current
Low-Speed I/O							
Clock Frequency (SCL)		fSCL		400		kHz	Default
				1000			Fast-mode+
Output Voltage (SCL and SDA)		VOL	0.0		0.4		Output low
		VOH	Vcc-0.5		Vcc+0.3		Output high
Input Voltage (SCL and SDA)		VIL	-0.3		0.3×Vcc	V	Input low
		VIH	0.7×Vcc		Vcc+0.5		Input high
Capacitance for SCL and SDA I/O Signal		Ci			14	pF	
Total Bus Capacitive Load for SCL and SDA	400kHz Clock Rate	Cb			100	pF	2, 3.0kΩ pull-up resistor, maximum
					200		2, 1.6kΩ pull-up resistor, maximum
Input Voltage/Current, LPMode/TxDis, ResetL, and ModSelL		VIL	-0.3		0.8	V	Input voltage, low
		VIH	2.0		Vcc+0.3		Input voltage, high
		Iin	-365		125	μA	Input current, 0V<VIN<Vcc
Output Voltage, ModPrsL, and IntL/RxLOSL		VOL	0.0		0.4	V	Output low, IOL = 2mA
		VOH	Vcc-0.5		Vcc+0.3		Output high, 10kΩ pull-up resistor to Host_Vcc

Notes:

1. The module will stay within its advertised power class for all supply voltages.
2. For 1000kHz clock rate.

Optical Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Notes
Power Supply – General						
Symbol Rate	Rbaud		27.95		GBd	
Modulation Format		DP-DQPSK				
Channel Frequency Range	Vc	191.4	193.7	196.1	THz	100GHz grid
	Vc	191.35	193.7	196.1	THz	50GHz grid
Channel Spacing	ΔVc		100		GHz	100GHz grid
	ΔVc		50		GHz	50GHz grid
Frequency Accuracy	δVc	-1.8		1.8	GHz	
Laser Intrinsic Linewidth	LW			500	kHz	Calculated based on FM noise Power Spectral Density (PSD) measurement
Side-Mode Suppression Ratio	SMSR	40			dB	No modulation
Relative Intensity Noise	RIN			-140	dB/Hz	Peak over 0.2GHz<f<10GHz
Transmitter						
Tx Output Power	PTx,out	-8		-4	dBm	
Tx Output Power Monitor Range	PTx,mon	-10		-2	dBm	
Tx Output Power Monitor Accuracy	$\delta PTx,mon$	-1.5		1.5	dB	Tx optical power monitor reading relative to actual Tx output power
Tx Output Power During Tuning or When Tx is Disabled	PTx,dark			-35	dBm	
Tx Spectral Excursion		-15		15	GHz	ITU-T G.698.2 §7.2.3 [11]
Tx Output Power Imbalance Between X and Y Polarizations	$\Delta PX/Y$			1.5	dB	
Tx XY Skew				6.0	ps	
Tx IQ Offset				-25	dB	
Tx IQ Imbalance				1.0	dB	
Tx Quadrature Error		-7.0		7.0	°	
Tx IQ Skew				1.5	ps	
Tx Error Vector Magnitude Mask Ratio				23	%	ITU-T G.698.2 §7.2.12 [11], with 24dB/0.1nm noise loading
Tx In-Band Optical Signal to Noise Ratio	OSNRin	40			dB/0.1nm	Under modulation, $ \Delta f < 60\text{GHz}$
Tx Out-of-Band Optical Signal to Noise Ratio	OSNRout	35			dB/0.1nm	Under modulation, $ \Delta f > 60\text{GHz}$, excl. side-mode peaks
Tx Reflectance				-20	dB	
Receiver						
Rx Total Input Power	PRx,tot	-30		3	dBm	Broadband
Rx Signal Input Power (Amplified)	PRx,sig	-18		1	dBm	Full Rx OSNR tolerance
		-22		3	dBm	1

Rx OSNR Tolerance	100G DQPSK SC		16.5			dB/0.1nm	Back-to-back, PRx,sig > -18dBm
	100G DQPSK RS		21.5				
CD Tolerance					2.4	ns/nm	OSNR penalty < 0.5dB
PMD Tolerance					10	Ps	
DGD Tolerance					20	Ps	
Tolerance to Change in SOP					50	krad/s	
PDL OSNR Penalty	1dB PDL				0.5	dB/0.1nm	Change in principal state of polarization < 1rad/ms
	2dB PDL				1.0		
	4dB PDL				3.0		
Rx Signal Input Power Transient Amplitude			-3		3	dB	2
Rx Signal Input Power Transient Rise/Fall Time			100			μs	3
Rx Signal Input Power (Unamplified)	100G DQPSK SC		-30		1	dBm	OSNR>35dB/0.1nm
	100G DQPSK RS		-24		1		
Rx Signal Input Power Monitor Range		PRx,mon(s)	-21		3	dBm	
Rx Signal Input Power Monitor Accuracy		δPRx,mon(s)	-2.5		2.5	dB	
Rx Total Input Power Monitor Range		PRx,mon(t)	-21		6	dBm	
Rx Total Input Power Monitor Accuracy		δPRx,mon(t)	-2.0		2.0	dB	
Rx Reflectance					-20	dB	

Notes:

1. Extended range. Rx signal input power range over which performance can be guaranteed with <1dB OSNR penalty relative to the Rx OSNR tolerance limit.
2. Peak excursion from steady state, transient within Rx signal input power (amplified) range, and OSNR penalty <0.5dB.
3. Rise/fall time for the above peak excursion, OSNR penalty <0.5dB.

Common Management Interface Specifications (CMIS)

Parameter	Symbol	Min.	Max.	Unit	Conditions	Notes
MgmtInitDuration			2000	ms	Time from power on, hot plug, or rising edge of reset until the high-to-low SDA transition of the start condition for the first acknowledged TWI transaction.	1
ResetL Assert Time		10		μs	Minimum pulse time on the ResetL signal to initiate a module reset.	
IntL/RxLOS Mode Change Time			100	ms	Time to change between IntL and RxLOS modes of the dual-mode signal IntL/RxLOS.	
LPMODE/TxDis Mode Change Time			100	ms	Time to change between LPMODE and TxDis modes of the LPMODE/TxDis signal.	
IntL Assert Time			200	ms	Time from occurrence of condition triggering IntL until VOUT:intL=VOL.	
IntL De-Assert Time			500	μs	Time from clear on read operation of associated flag until VOUT:IntL=VOH. This includes de-assert times for RxLOS, Tx Fault, and other flag bits.	2
RxLOS Assert Time			1	ms	Time from RxLOS condition present to RxLOS bit set (value = 1b) and IntL asserted.	3
RxLOS De-Assert Time			3	ms	Time from optical signal above the LOS de-assert threshold to when the module releases the RxLOS signal to high.	
Tx Disable Assert Time			1	ms	Time from Tx Disable bit set (value = 1b) until optical output falls below 10% of nominal.	4
Tx Disable De-Assert Time			10	s	Time from Tx Disable bit cleared (value = 0b) until optical output rises above 90% of nominal.	4
Tx Fault Assert Time			200	ms	Time from Tx Fault state to Tx Fault bit set (value = 1b) and IntL asserted.	
Flag Assert Time			200	ms	Time from occurrence and condition triggering flag to associated flag bit set (value = 1b) and IntL asserted.	
Mask Assert Time			100	ms	Time from mask bit set (value = 1b) until the associated IntL assertion is inhibited.	5
Mask De-Assert Time			100	ms	Time from mask bit cleared (value = 0b) until associated IntL operation resumes.	5
Data Path Tx Turn On Max. Duration	See CMIS memory P01h: B168				Maximum duration of Tx Turn On state.	6
Data Path Tx Turn Off Max. Duration	See CMIS memory P01h: B168				Maximum duration of Tx Turn Off state.	6
Data Path De-Init. Max. Duration	See CMIS memory P01h: B144				Maximum duration of DataPathDelnit state.	6
Data Path Init. Max. Duration	See CMIS memory P01h: B144				Maximum duration of DataPathInit state.	6
Module Pwr Up Max. Duration	See CMIS memory P01h: B167				Maximum duration of Module Pwr Up state.	7
Module Pwr Dn Max. Duration	See CMIS memory P01h: B167				Maximum duration of Module Pwr Dn state.	7
I/O Timing for Squelch & Disable						
Rx Squelch Assert Time			15	ms	Time from loss of Rx input signal until the squelched output condition is reached.	
Rx Squelch De-Assert Time			15	ms	Time from resumption of Rx input signals until normal Rx output condition is reached.	
Tx Squelch Assert Time			400	ms	Time from loss of Tx input signal until the squelched output condition is reached.	
Tx Squelch De-Assert Time			10	s	Time from resumption of Tx input signal until the normal Tx output condition is reached.	

Rx Output Disable Assert Time			100	ms	Time from Rx Output Disable bit set (value = 1b) until Rx output falls below 10% of nominal.	4
Rx Output Disable De-Assert Time			100	ms	Time from Rx Output Disable bit cleared to (value = 0b) until Rx output rises above 90% of nominal.	4
Squelch Disable Assert Time			100	ms	This applies to Rx and Tx Squelch and is the time from bit set (value = 1b) until squelch functionality is disabled.	4
Squelch Disable De-Assert Time			100	ms	This applies to Rx and Tx Squelch and is the time from bit cleared (value = 0b) until squelch functionality is enabled.	4

Notes:

1. "Power on" is defined as the instant when supply voltages reach and remain at or above the minimum level specified.
2. Measured from the rising edge of SDA during STOP sequence of write transaction.
3. RxLOS condition is defined as a Rx input power below the threshold or DSP loss of signal.
4. Measured from low-to-high SDA signal transition of the STOP condition of the write transaction.
5. Measured from low-to-high SDA edge of the STOP condition of the write transaction.
6. Measured from the low-to-high SDA edge of the stop condition of the write transaction until the IntL for the state change VOUT:IntL=VOL, unless the module advertises a less than 1ms duration in which case there is no defined measurement.
7. Measured from the low-to-high SDA edge of the stop condition of the write transaction until the IntL for the state change VOUT:IntL=VOL.

Optical Timing Characteristics

Parameter	Symbol	Min.	Max.	Unit	Conditions	Notes
Tx Turn On Time			10	s	Warm Start	1
			120	s	Cold Start	
Rx Acquisition Time			30	ms	Warm Start	
			120	s	Cold Start	
Tx/Rx Channel Tuning Time			30	s		

Notes:

1. Assumes the Tx/Rx laser is already tuned to the correct frequency.

Pin Descriptions

Pin	Logic	Symbol	Name/Description	Plug Sequence	Notes
1		GND	Module Ground.	1	1
2	CML-I	Tx2-	Transmitter Inverted Data Input.	3	
3	CML-I	Tx2+	Transmitter Non-Inverted Data Input.	3	
4		GND	Module Ground.	1	1
5	CML-I	Tx4-	Transmitter Inverted Data Input.	3	
6	CML-I	Tx4+	Transmitter Non-Inverted Data Input.	3	
7		GND	Module Ground.	1	1
8	LVTTL-I	ModSelL	Module Select.	3	
9	LVTTL-I	ResetL	Module Reset.	3	
10		VccRx	+3.3V Receiver Power Supply.	2	2
11	LVC MOS-I/O	SCL	2-Wire Serial Interface Clock.	3	
12	LVC MOS-I/O	SDA	2-Wire Serial Interface Data.	3	
13		GND	Module Ground.	1	1
14	CML-O	Rx3+	Receiver Non-Inverted Data Output.	3	
15	CML-O	Rx3-	Receiver Inverted Data Output.	3	
16		GND	Module Ground.	1	1
17	CML-O	Rx1+	Receiver Non-Inverted Data Output.	3	
18	CML-O	Rx1-	Receiver Inverted Data Output.	3	
19		GND	Module Ground.	1	1
20		GND	Module Ground.	1	1
21	CML-O	Rx2-	Receiver Inverted Data Output.	3	
22	CML-O	Rx2+	Receiver Non-Inverted Data Output.	3	
23		GND	Module Ground.	1	1
24	CML-O	Rx4-	Receiver Inverted Data Output.	3	
25	CML-O	Rx4+	Receiver Non-Inverted Data Output.	3	
26		GND	Module Ground.	1	1
27	LVTTL-O	ModPrsL	Module Present.	3	
28	LVTTL-O	IntL/RxLOSL	Interrupt. Optionally configurable as RxLOSL via the management interface (CMIS).	3	
29		VccTx	+3.3V Transmitter Power Supply.	2	2
30		Vcc1	+3.3V Power Supply.	2	2
31	LVTTL-I	LPMode/TxDis	Low-Power Mode. Optionally configurable as TxDis via the management interface (CMIS).	3	
32		GND	Module Ground.	1	1
33	CML-I	Tx3+	Transmitter Non-Inverted Data Input.	3	
34	CML-I	Tx3-	Transmitter Inverted Data Input.	3	
35		GND	Module Ground.	1	1
36	CML-I	Tx1+	Transmitter Non-Inverted Data Input.	3	
37	CML-I	Tx1-	Transmitter Inverted Data Input.	3	
38		GND	Module Ground.	1	1

Notes:

- 1. GND is the symbol for signal and supply (power) common for the module. All are common within the module, and all module voltages are referenced to this potential unless otherwise noted. Connect these directly to the host board signal common ground plane.
- 2. VccRx, Vcc1, and VccTx are applied concurrently and may be internally connected within the module in any combination.
- 3. Plug Sequence specifies the mating sequence of the host connector and module. The sequence is 1, 2, and 3. See figure below for pad locations.

Electrical Pad Layout



Block Diagram



Mechanical Specifications



About Skylane Optics

Skylane is a leading provider of transceivers for optical communication.

We offer an extensive portfolio for the enterprise, access, datacenter and metropolitan fiber optical market as well as for smart home applications and home networks.

We cover the European, South American and North American market with a strong partner network and have offices in Belgium, Brazil, Sweden and USA.

Our offerings are characterized by high quality and performance. In combination with our strong technical support, we enable our customers to build cost optimized network solutions.

We offer an extensive range of high-quality products including transceivers (Optical and copper), Active Optical Cable (AOC), Direct Attach Cable (DAC), Mux/Demux, Coding Box.

